

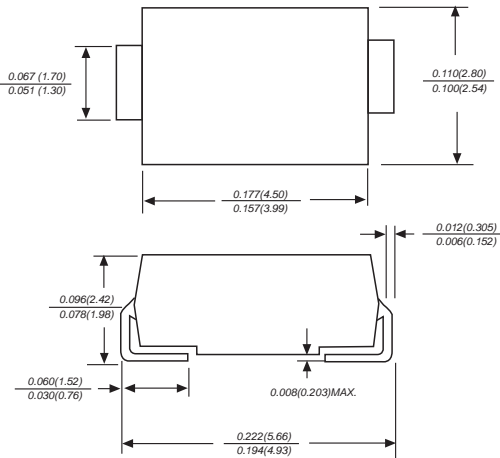


# SS12 THRU SS1200

## SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts Forward Current - 1.0 Ampere

### DO-214AC/SMA



Dimensions in inches and (millimeters)

### FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ Built-in strain relief, ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed: 250°C/10 seconds at terminals

### MECHANICAL DATA

**Case:** JEDEC DO-214AC molded plastic body  
**Terminals:** leads solderable per MIL-STD-750, Method 2026

**Polarity:** Color band denotes cathode end

**Mounting Position:** Any

**Weight:** 0.002 ounce, 0.07 grams

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.  
Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

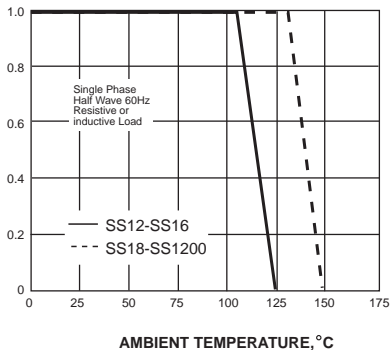
MDD Catalog Number	SYMBOLS	SS12	SS13	SS14	SS15	SS16	SS18	SS110	SS1150	SS1200	UNITS
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	50	60	80	100	150	200	VOLTS
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	35	42	56	70	105	140	VOLTS
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	50	60	80	100	150	200	VOLTS
Maximum average forward rectified current at T <sub>L</sub> (see fig.1)	I <sub>(AV)</sub>	1.0									Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	30.0									Amps
Maximum instantaneous forward voltage at 1.0A	V <sub>F</sub>	0.45	0.55	0.70		0.85			0.95	Volts	
Maximum DC reverse current      T <sub>A</sub> =25°C at rated DC blocking voltage      T <sub>A</sub> =100°C	I <sub>R</sub>	0.5						0.2		mA	
		10.0			5.0			2.0			
Typical junction capacitance (NOTE 1)	C <sub>J</sub>	110			90						pF
Typical thermal resistance (NOTE 2)	R <sub>θJA</sub>	88.0									°C/W
Operating junction temperature range	T <sub>J</sub>	-50 to +125					-50 to +150				°C
Storage temperature range	T <sub>STG</sub>	-50 to +150									°C

**Note:** 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.  
2. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

# RATINGS AND CHARACTERISTIC CURVES SS12 THRU SS1200

AVERAGE FORWARD RECTIFIED CURRENT,  
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



PEAK FORWARD SURGE CURRENT,  
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

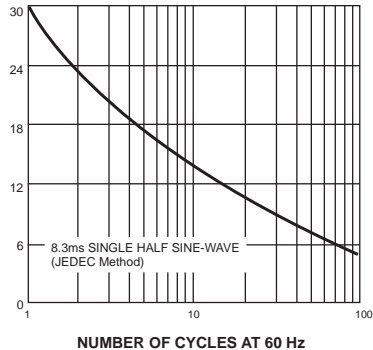
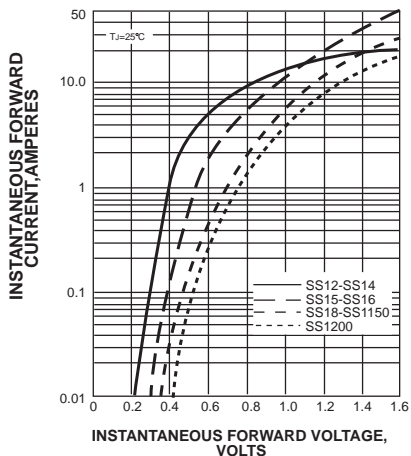


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



INSTANTANEOUS REVERSE CURRENT,  
MILLIAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS

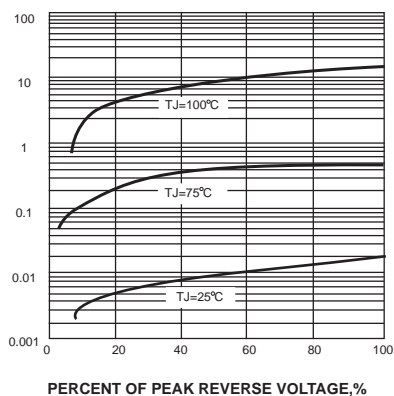
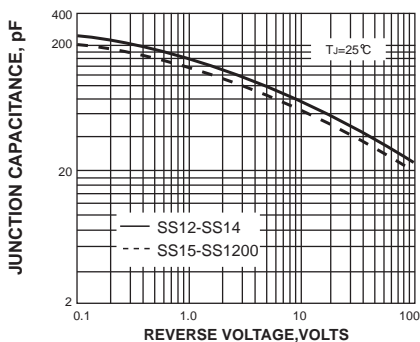


FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE,  
°C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

